

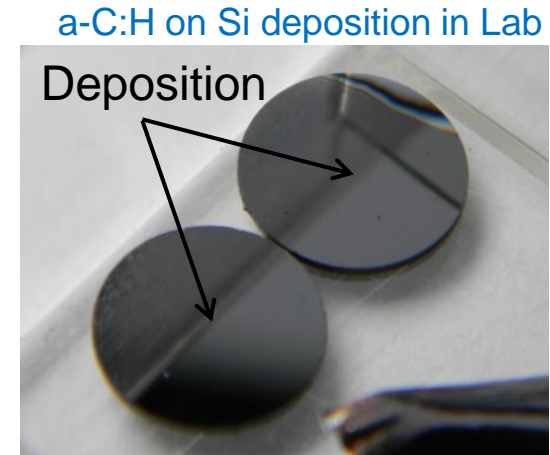


Investigations of Porosity Enhanced Removal of Fuel Containing Carbon Codeposits by Thermo-Chemical Removal

16. March 2012 | Sören Möller, A. Kreter, H.G. Esser and U. Samm

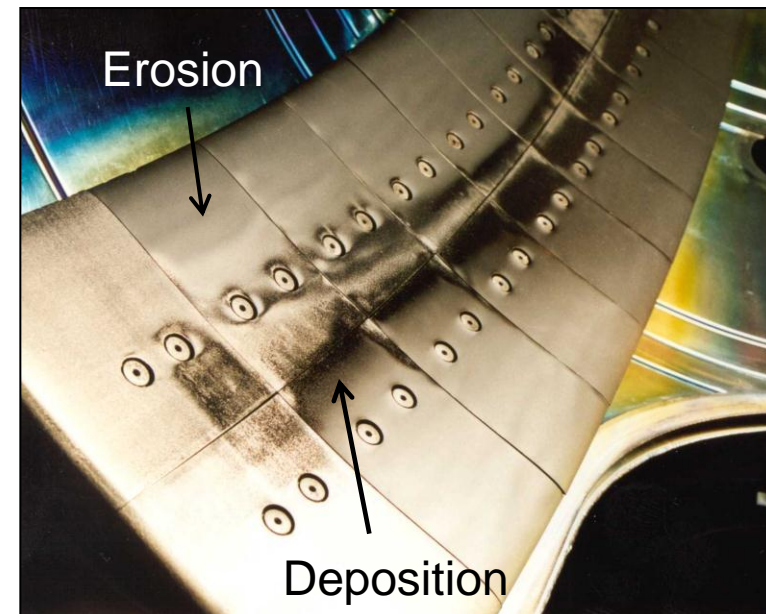
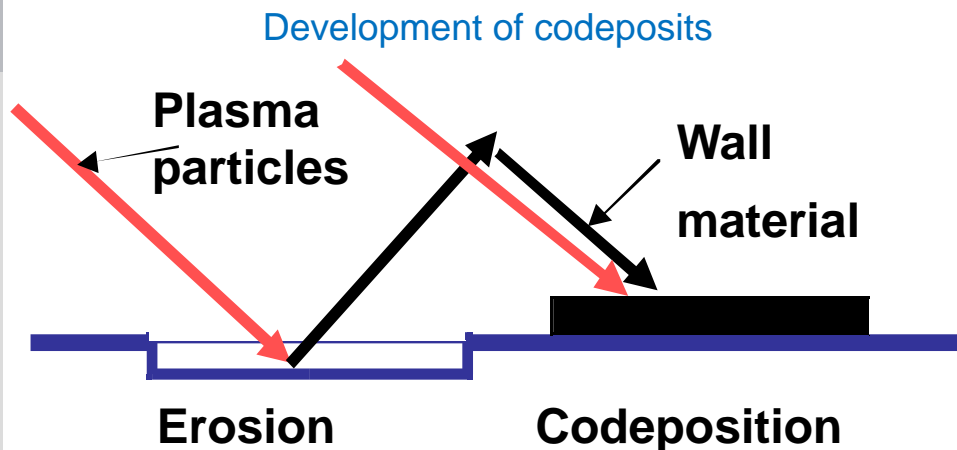
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- Carbon based wall materials release carbon (C) due to the contact with the hydrogen plasmas in fusion devices
 - **amorphous hydrogenated carbon layers** (a-C:H) are formed on reactor surfaces
 - Tritium-Codeposition (T)*
 - Fuel retention and safety problems (e.g. ITER)*



Deposition in Tokamak

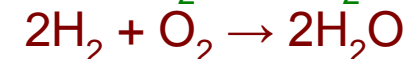
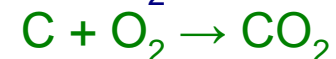
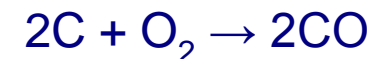
→ Removal of codeposits necessary





- **Treatment of codeposits with heat and chemical reactants**
 - Very homogenous and B-Field compatible
 - Needs high wall temperatures ($>300^{\circ}\text{C}$ for O_2) and pressures ($>5\text{mbar}$) to be effective
 - Most effective with O_2 or NO_2 , then known as oxygen baking
 - Removal of Carbon and fuel isotopes (H,D,T) is partially decoupled
 - Lack of in-depth theory describing the process, so far

Typical reactions



- **Goals of this study**
 - Develop a theory for the process
 - Compare it with available data (mainly from Davis, Univ. of Toronto)
 - Derive suggestions for maximum removal rate in fusion devices

Initially nanopores form ~10% of the layer volume

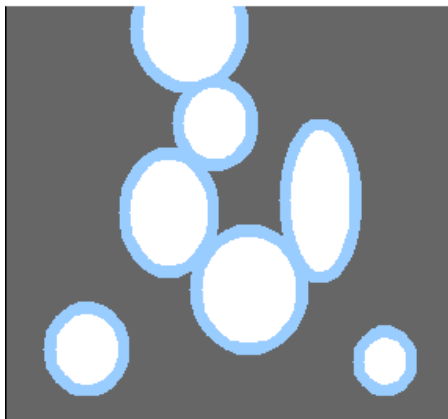
Open pores form a network which is accessible from the surface

Pore surface area, H/C and mass density of layers are connected

By Thermo-Chemical Erosion:

- The pore walls adsorb removal gas
- *Pore sizes and thus the porosity increase*
- *Thickness reduces only slowly*

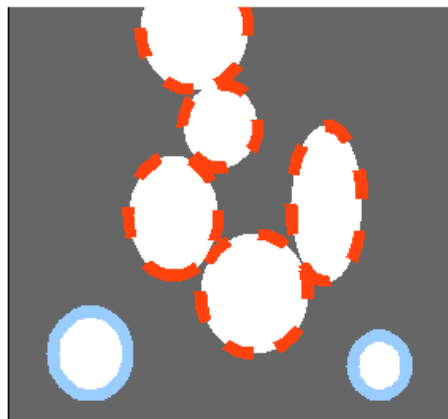
Surface



TCE



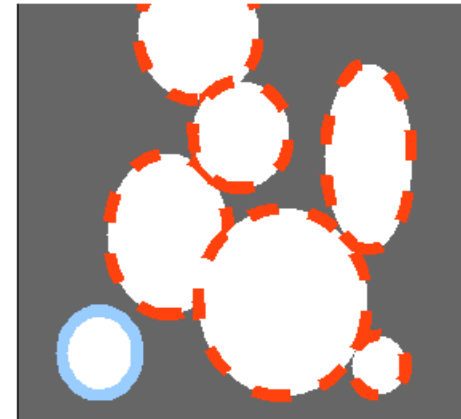
Surface



TCE



Surface



Analytical Removal equation

The general description can be derived from differential reaction-diffusion equation

$$Dn''(x) - kn(x) = 0$$

Only for layers $\gg 25\mu\text{m}$ or $T_s \sim 1000\text{K}$ the diffusion limits reaction rate, otherwise diffusion is fast enough to be neglected

Homogenous 2nd order chemical reaction equation in the **reaction limited** regime of removal rate of atoms per area and time:

R

Thickness of layer

Number of reacting removal gas particles

$$R = \int_0^z k(T_s) \times n_{\text{Gas}}(x) \times n_{D,C}(x) dx \xrightarrow{\text{reaction limited}} R = k n_{\text{Gas}} n_{D,C} \int_0^z dx \Rightarrow$$

Chemical reaction rate (Arrhenius)

$$R(T_s, p_{\text{Gas}}, z) = P * \sqrt{\frac{\pi k_B T_s}{2m_{\text{Molecule}}}} * e^{-\frac{E_A}{k_B T_s}} \times \frac{z * C_{\text{Por}}}{V_{\text{Molecule}}} * \frac{K_L p_{\text{Gas}}}{1 + K_L p_{\text{Gas}}} \times n_{D,C}$$

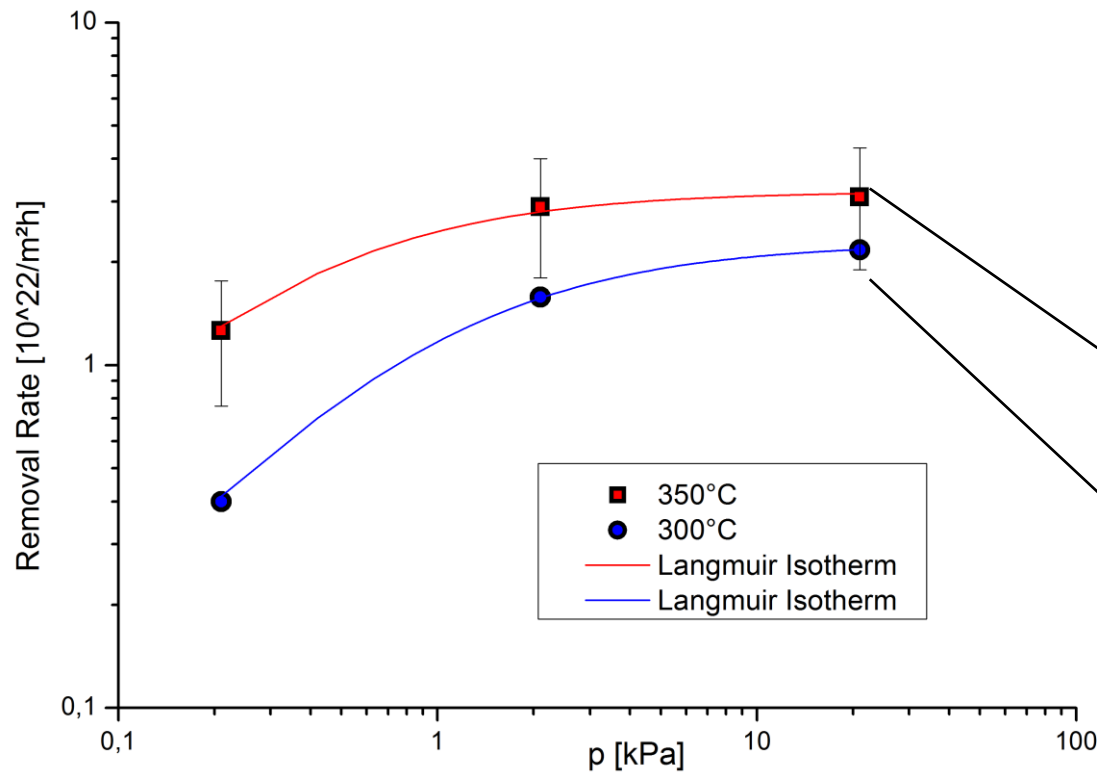
Pore volume per area

Maximum particles per area

Langmuir adsorption of particles in pores



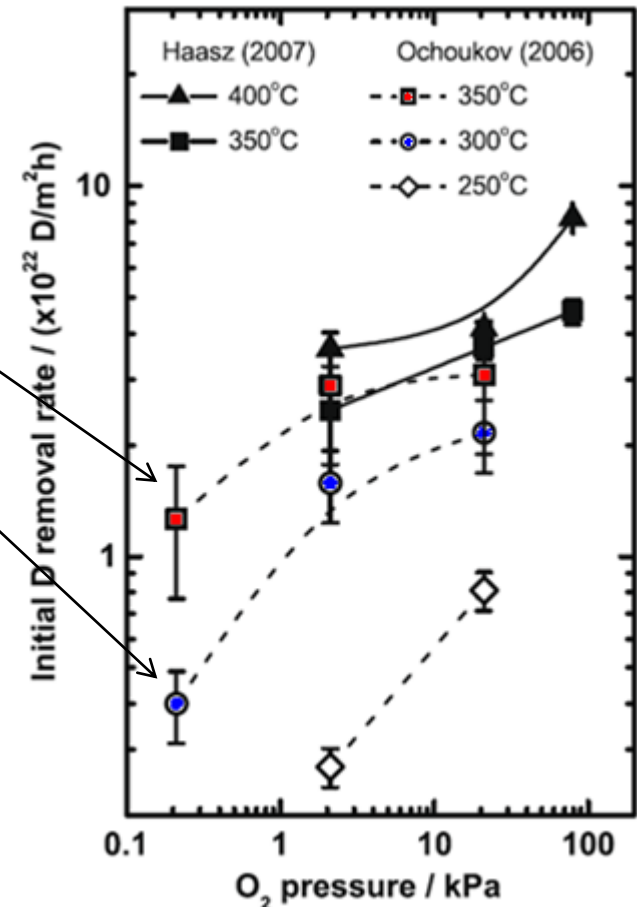
Comparison with available experimental data



Fit is in agreement with data

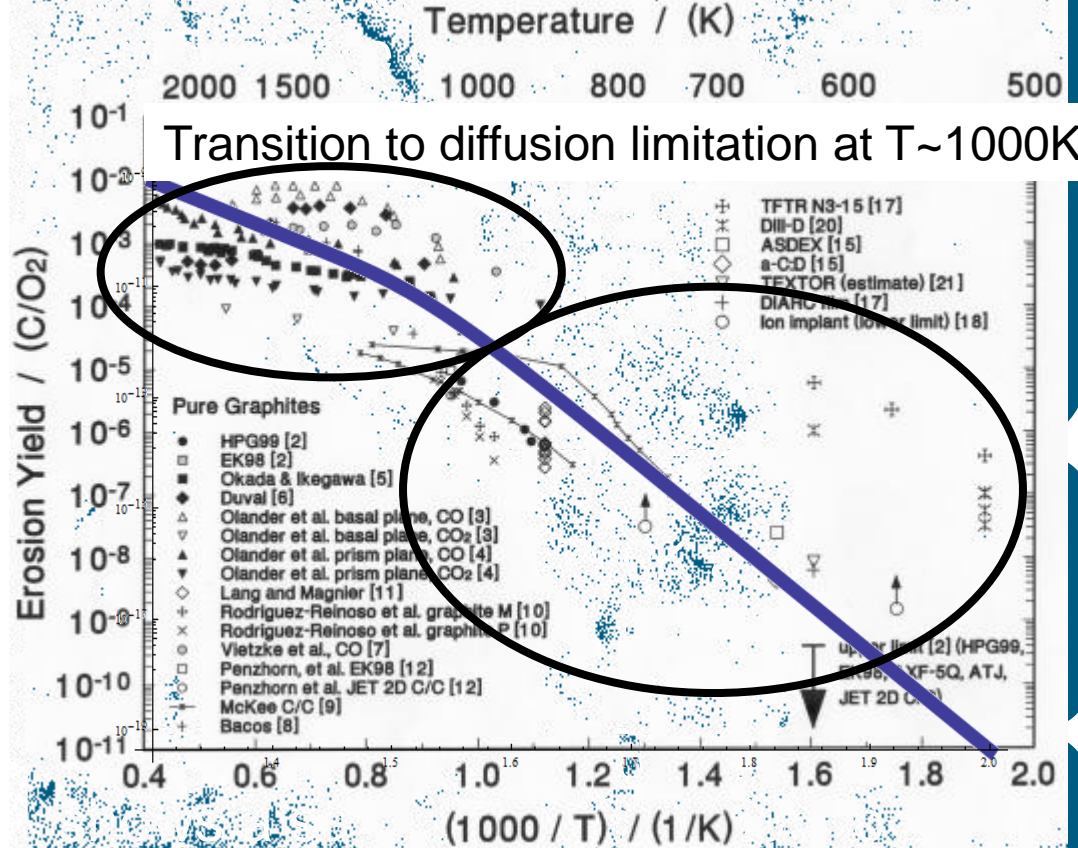
$$R = C(T_S, z) * \frac{K_{LP} p_{gas}}{1 + K_{LP} p_{gas}}$$

Pressure dependence of the atom removal rate



[Davis, JNM 390-391 (2009), 532-537]

Arrhenius dependence of atom

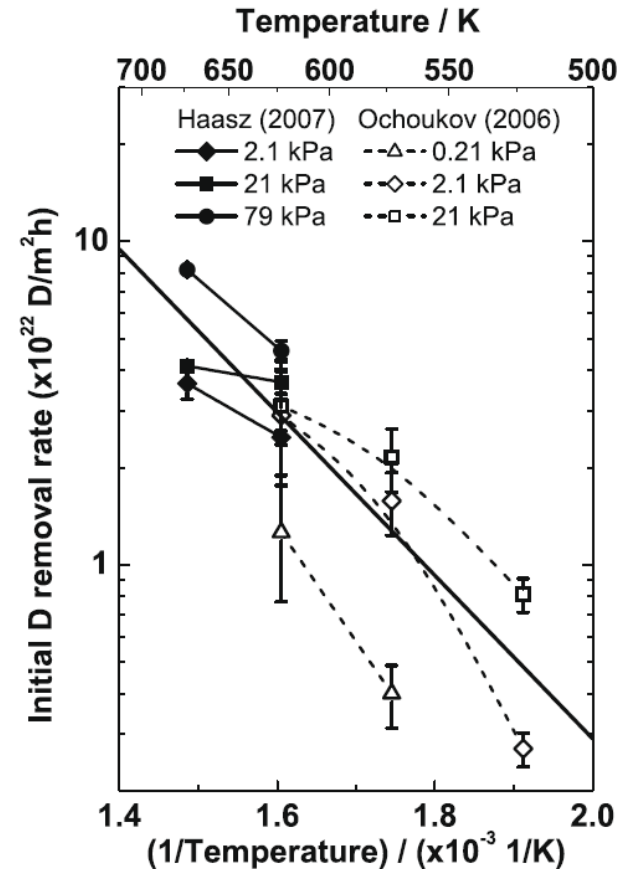


transition from a reaction limited to a diffusion limited process at high temperatures

$$R = C(Z, p_{\text{gas}}) * \frac{\pi k_B T_s}{2m_{\text{Molecule}}} * e^{-\frac{E_A}{k_B T_s}}$$

[Davis, Phys. Scr. 91 (2000), 33-35]

Temperature dependence of the atom removal rate



[Davis, JNM 390-391 (2009), 532-537]

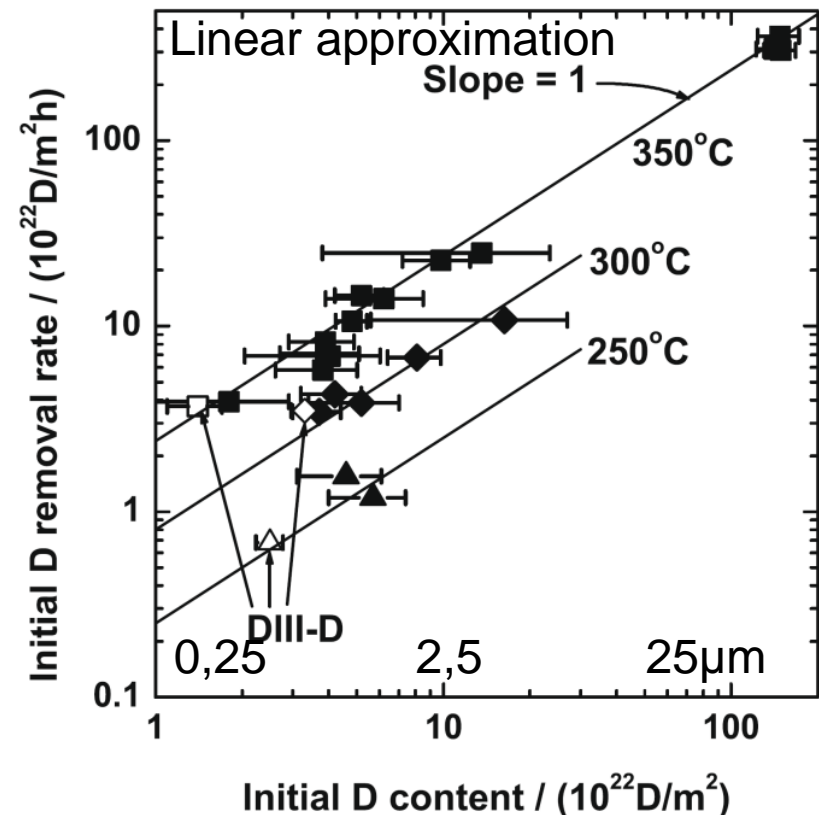
A linear dependence of the removal rate on the initial atom content (which is proportional to the layer thickness) is seen in a study by Davis

The model shows a linear dependence with thickness z

$$R = C(T_S, p_{Gas}) * z$$

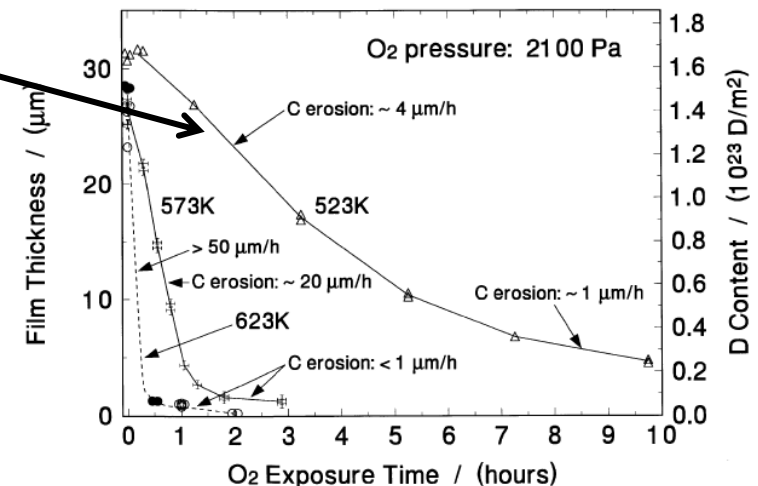
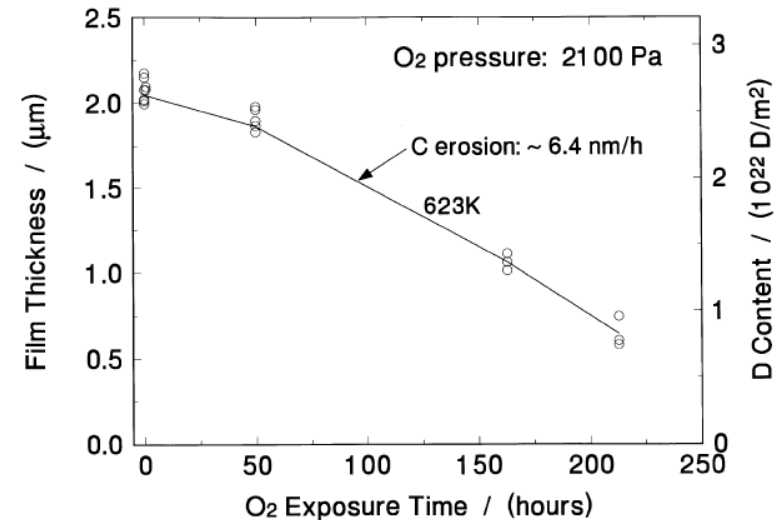
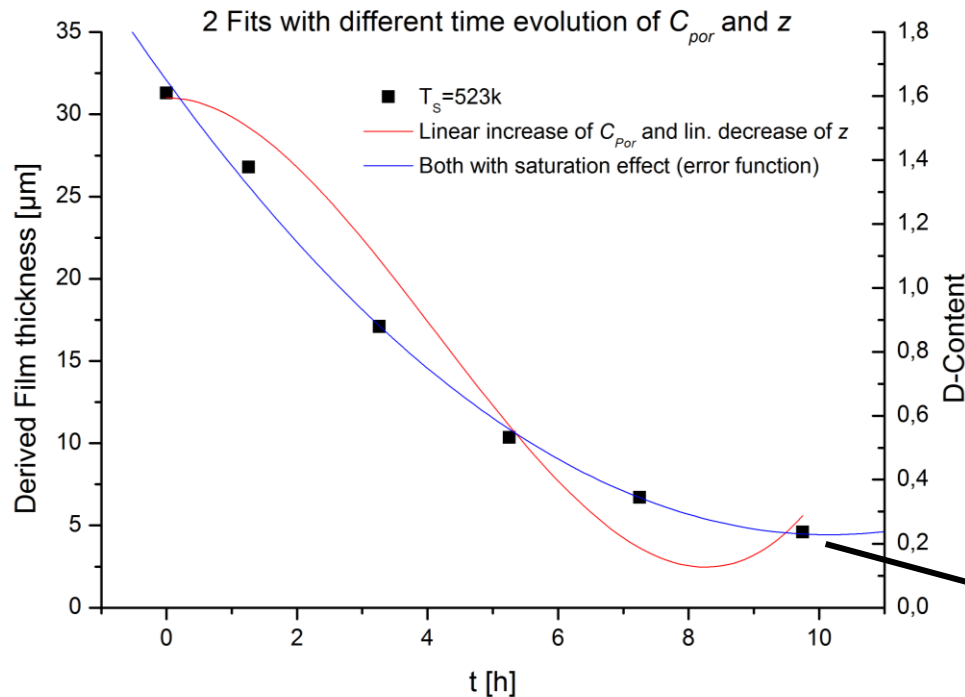
A diffusion limitation does not appear at thicknesses $< 25\mu\text{m}$, when considering Davis' results

Effect of the initial areal atom density, i.e. thickness, on the removal rate



[Davis, JNM 390-391 (2009), 532-537]

Time evolution of the layer D content



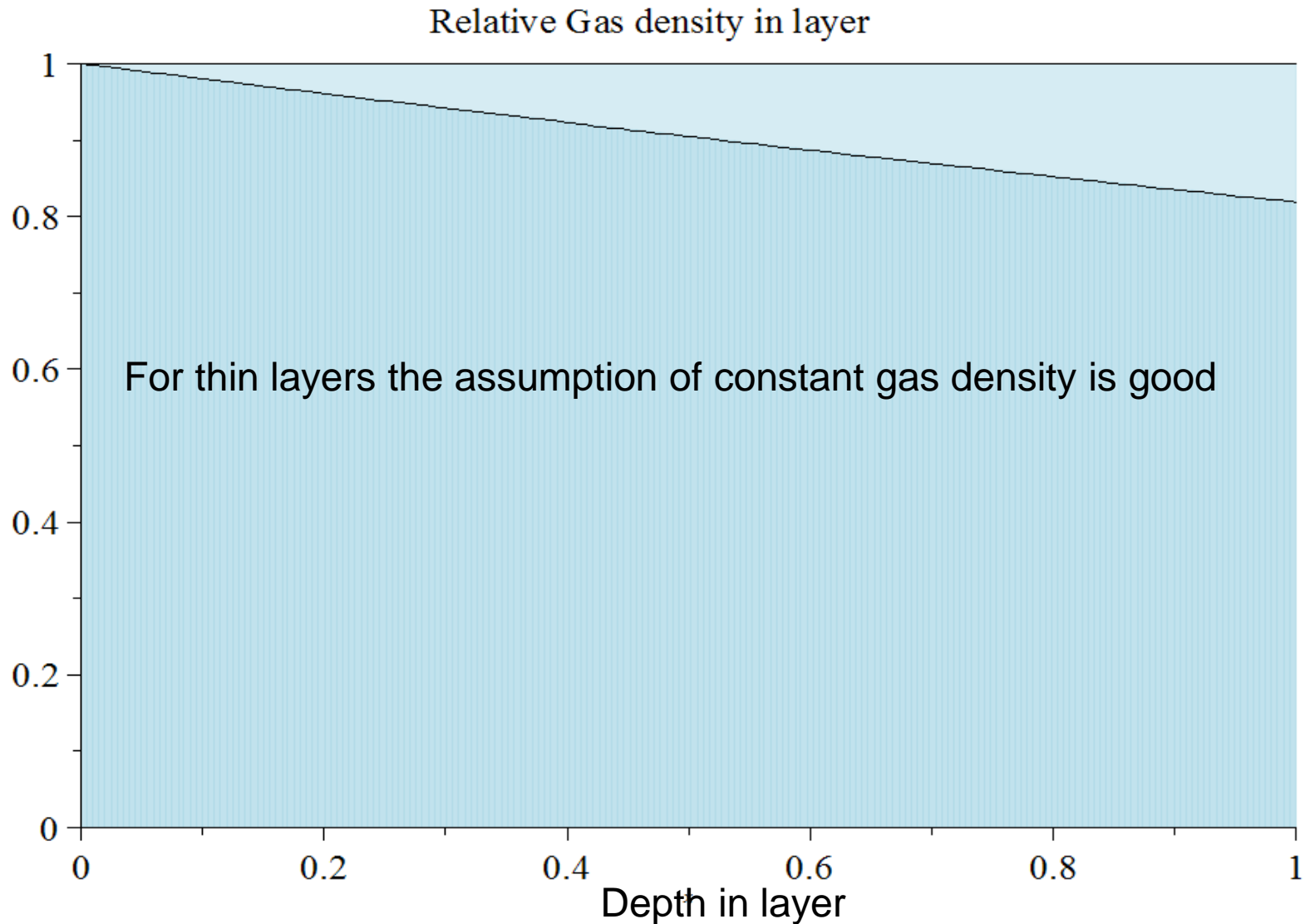
$$R = C(T_s, p_{Gas}) * z(t) * C_{Por}(t)$$

$$R = C(T_s, p_{Gas}) * z(t) * C_{Por}(t)$$

This behaviour is in contrast to the constant removal rate of plasma based methods

[Haasz, Davis, JNM 256 (1998), 65-68]

- A physical, analytical model describing the removal process has been developed
- Removal rate increase with both temperature and pressure
 - use highest possible values for Thermo-Chemical removal, but yield decreases with $p_{\text{Gas}} > 20\text{mbar}$, $T_s > 700\text{K}$
- Removal rate is mostly proportional to layer thickness
 - Thermo-Chemical removal should be applied on a medium-term basis (e.g. 10 ITER discharges), with plasma cleaning of retained oxygen and layer remainders afterwards
- A combination of thermo-chemical removal with plasma removal can be the fastest removal method, when switching at the right time
 - A modelling software including the derived formulas and parameters is planned, in order to predict removal rates and times for future devices



$$Dn''(x) - kn(x) = 0$$

1-D differential equation for the concentration of the removal gas n in dependence of the depth x at steady state

- Diffusion coefficient D , Arrhenius-type reaction coefficient k

$$\begin{aligned} n(0) &= C_{por} \times \frac{K_L p_{Gas}}{1 + K_L p_{Gas}} \\ n(\infty) &= 0 \end{aligned}$$

Boundary conditions

- At the layer surface ($x=0$) gas concentration is determined by the outer gas density and relative volume porosity C_{por}
- A saturation with pressure is described by Langmuir Adsorption with coefficient K_L
- At infinite thickness no gas is left over

$$n(x) = \left(C_{por} \times \frac{p_{Gas}}{k_B T} \right) \times e^{-x \sqrt{k/D}}$$

Solution $n(x)$ shows an exponential concentration decrease with depth x of layer

The total amount of gas in the layer N is the integral of n over the layer thickness z

$$N(z) = \int_0^z n(x) dx = \sqrt{\frac{D}{k}} (1 - e^{-z\sqrt{\frac{k}{D}}}) (C_{Por} \times \frac{K_L p_{Gas}}{1 + K_L p_{Gas}})]$$

Total removal rate R is given by amount of removal gas N times the probability of a reaction per time k

$$R = k(T_S) \times N(z, C_{Por}) \times N_{D,C} \Rightarrow$$

$$R = P e^{-\frac{E_A}{T_S k_B}} \times \sqrt{\frac{D}{k}} (1 - e^{-z\sqrt{\frac{k}{D}}}) \left[C_{Por} \times \frac{K_L p_{Gas}}{1 + K_L p_{Gas}} \right] \times N_{D,C}$$

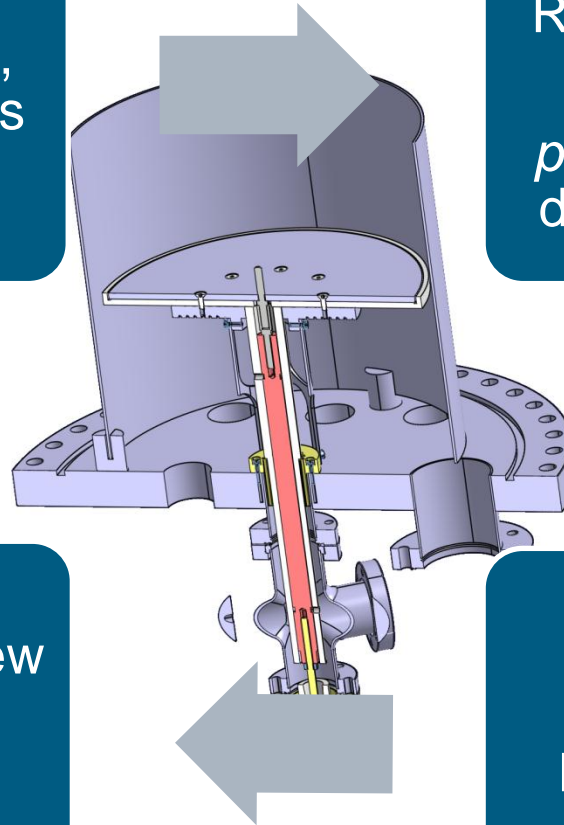
In total 5 free parameters remain, which have to be determined experimentally

- Temperature dependence: P , E_A
- Porosity dependent values: C_{Por} , K_L , D

Experimental test of the thickness dependence

Laboratory carbon layers on Si for constant and known layer properties, but different thicknesses (5 steps from 200-3200nm)

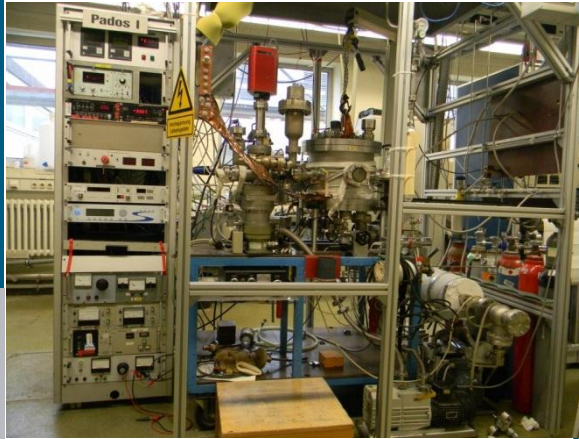
Thermo-Chemical Removal with oxygen at $T_S=350^\circ\text{C}$ and $p_{\text{Gas}}=10\text{mbar}$ with same durations t for all layers



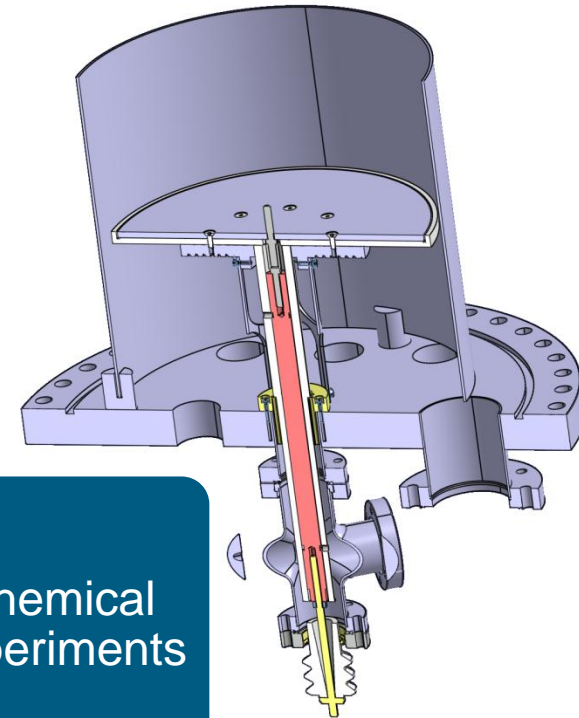
Fitting of model to the new experimental data and comparison with other experiments

Removal rate determination by Ellipsometry, Profilometry, μg -scale with pre/post measurements

Photo of PADOS



CAD image of new internal structure



Vacuum device
PADOS has 2
distinct
configurations

RF-Glow Discharge
Plasmas for
deposition and
cleaning

Thermo-Chemical
removal experiments

Measurement of T_{wall}
(deposition parameter)
High deposition rates ($1\mu\text{m/h}$)
Sheath potentials down to
 $\sim 100\text{V}$ for layer density control
Thick layers ($>\text{several } \mu\text{m}$)

Capillary tube for $<1\text{bar}$
gas analysis by QMS
 $T_{\text{wall}} = 25\dots 700^\circ\text{C}$
Toxic and explosive gases
Little background deposits

Polished Silicon Substrates

- Low surface roughness
- Good adhesion of a-C:H also for thick layers
- Large area >40cm² samples available
- Advantages for NRA, QMS, Ellipsometry, Profilometry, µg-scale

All Layers have similar Properties

- Deposition in similar condition RF-discharges in CD₄ in PADOS
 - All free parameters, except *z (thickness)*, are similar for all layers
- 5 different layer thicknesses by 5 different deposition durations

Layer Property Determination

- Ellipsometry and Profilometry for thickness measurement
- Areal Carbon density by µg-scale and thickness
- NRA measurements planned for D determination

Thermo-Chemical removal in Oxygen

- 10mbar, $T_{\text{wall}} = 350^{\circ}\text{C}$
- Same conditions for all layer thicknesses

Mass spectrometry

- Determination of exhaust products
- Safety aspects of oxygen cleaning
- Assessment of thickness effects

Fitting of Model to Data

- Test of model with new data
- Comparison with other oxygen experiments at similar conditions (e.g. Davis, my Diploma thesis)